

L Number	Hits	Search Text	DB	Time stamp
114	4865	pin adj diode	USPAT; US-PGPUB	2004/08/23 14:21
115	1349	(pin adj diode) and gate	USPAT; US-PGPUB	2004/08/23 14:21
116	160	((pin adj diode) and gate ) and gate same	USPAT; US-PGPUB	2004/08/23 14:22
117	1873	pin and insulat\$ pin adj photodiode	USPAT; US-PGPUB	2004/08/23 14:25
118	801	(pin adj photodiode ) and (gate or electrode)	USPAT; US-PGPUB	2004/08/23 14:26
119	190	((pin adj photodiode ) and (gate or electrode)) and (pin adj photodiode) same	USPAT; US-PGPUB	2004/08/23 14:26
120	99	((pin adj photodiode ) and (gate or electrode)) and (pin adj photodiode) same	USPAT; US-PGPUB	2004/08/23 14:26
130	643	(gate or electrode)) and insulat\$ 257/233	USPAT; US-PGPUB	2004/08/23 14:53
131	8	257/233 and pin adj (diode or photodiode)	USPAT; US-PGPUB	2004/08/23 14:53
-	1781	pin adj photodiode	USPAT; US-PGPUB	2004/08/23 14:25
-	502	(pin adj photodiode) and electrode	USPAT; US-PGPUB	2004/04/27 12:26
-	5	((pin adj photodiode) and electrode) and	USPAT; US-PGPUB	2004/04/27 12:26
-	8387	anti adj reflection adj layer mems	USPAT; US-PGPUB	2004/04/28 10:44
-	2827	mems and electrode	USPAT; US-PGPUB	2004/04/28 11:11
-	1	("6566617").PN.	USPAT; US-PGPUB	2004/04/28 11:18
-	1	("6504118").PN.	USPAT; US-PGPUB	2004/04/28 14:34
-	1	("6225165").PN.	USPAT; US-PGPUB	2004/04/28 14:34
-	1792	pin adj photodiode	USPAT; US-PGPUB	2004/05/06 11:01
-	2	(pin adj photodiode) and substrate and electrode and gate and (gate adj insulation) and intrinsic	USPAT; US-PGPUB	2004/05/06 11:04
-	2	(pin adj photodiode) and substrate and electrode and gate and (gate adj insulation)	USPAT; US-PGPUB	2004/05/06 11:04
-	105	(pin adj photodiode) and substrate and electrode and gate	USPAT; US-PGPUB	2004/05/06 11:04
-	83	((pin adj photodiode) and substrate and electrode and gate ) and insulat\$	USPAT; US-PGPUB	2004/05/06 11:04